NSN 5961-01-267-7098

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View Online at https://aerobasegroup.com/nsn/5961-01-267-7098 **Inclosure Material:** Metal **Overall Length:** 0.370 inches **Overall Height:** 0.050 inches **Overall Width:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: Hpac-100 **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 900.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter and 220.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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